



CSD19536KTT 100 V N-Channel NexFET™ Power MOSFET

1 Features

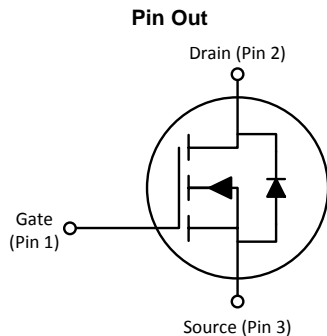
- Ultra-Low Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb-Free Terminal Plating
- RoHS Compliant
- Halogen Free
- D²PAK Plastic Package

2 Applications

- Secondary Side Synchronous Rectifier
- Hot Swap
- Motor Control

3 Description

This 100 V, 2.0 mΩ, D²PAK (TO-263) NexFET™ power MOSFET is designed to minimize losses in power conversion applications.



Product Summary

$T_A = 25^\circ\text{C}$		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-source voltage	100		V
Q_g	Gate charge total (10 V)	118		nC
Q_{gd}	Gate charge gate-to-drain	17		nC
$R_{DS(on)}$	Drain-to-source on-resistance	$V_{GS} = 6\text{ V}$	2.2	mΩ
		$V_{GS} = 10\text{ V}$	2.0	mΩ
$V_{GS(th)}$	Threshold voltage	2.5		V

Ordering Information⁽¹⁾

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD19536KTT	500	13-Inch Reel	D ² PAK Plastic Package	Tape and Reel
CSD19536KTTT	50			

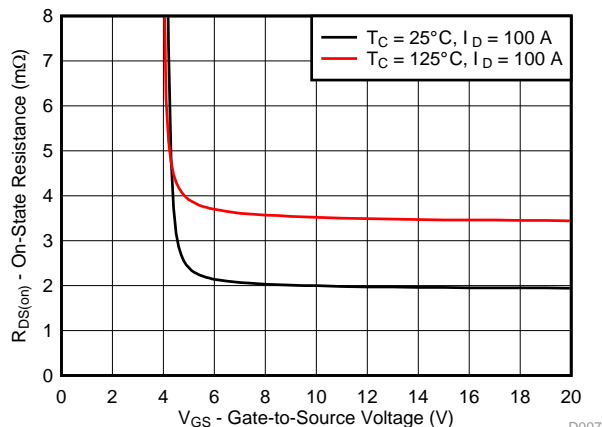
(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$		VALUE	UNIT
V_{DS}	Drain-to-source voltage	100	V
V_{GS}	Gate-to-source voltage	± 20	V
I_D	Continuous drain current (package limited)	200	A
	Continuous drain current (silicon limited), $T_C = 25^\circ\text{C}$	272	
	Continuous drain current (silicon limited), $T_C = 100^\circ\text{C}$	192	
I_{DM}	Pulsed drain current ⁽¹⁾	400	A
P_D	Power dissipation	375	W
T_J , T_{stg}	Operating junction, Storage temperature	-55 to 175	$^\circ\text{C}$
E_{AS}	Avalanche energy, single pulse $I_D = 127\text{ A}$, $L = 0.1\text{ mH}$, $R_G = 25\text{ }\Omega$	806	mJ

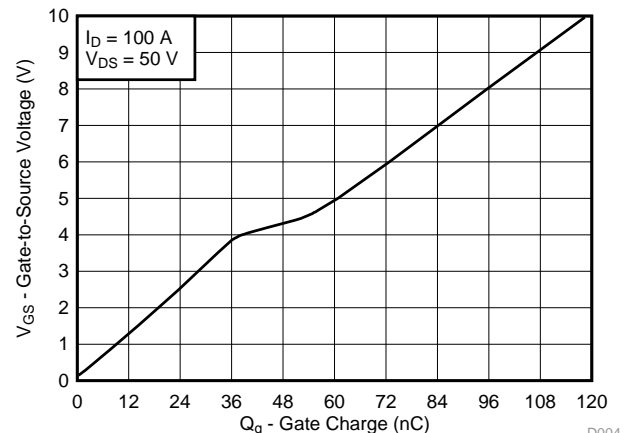
(1) Max $R_{\theta JC} = 0.4^\circ\text{C/W}$, Pulse duration $\leq 100\text{ }\mu\text{s}$, Duty cycle $\leq 1\%$.

$R_{DS(on)}$ vs V_{GS}



D007

Gate Charge



D004



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4 Revision History

Changes from Original (March 2015) to Revision A	Page
• Added Community Resources	7
• Added PCB and stencil drawings in Mechanical, Packaging, and Orderable Information	8

5 Specifications

5.1 Electrical Characteristics

($T_A = 25^\circ\text{C}$ unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
BV _{DSS}	Drain-to-source voltage	V _{GS} = 0 V, I _D = 250 μA	100			V
I _{DSS}	Drain-to-source leakage current	V _{GS} = 0 V, V _{DS} = 80 V			1	μA
I _{GSS}	Gate-to-source leakage current	V _{DS} = 0 V, V _{GS} = 20 V			100	nA
V _{GS(th)}	Gate-to-source threshold voltage	V _{DS} = V _{GS} , I _D = 250 μA	2.1	2.5	3.2	V
R _{DS(on)}	Drain-to-source on-resistance	V _{GS} = 6 V, I _D = 100 A	2.2		2.8	mΩ
		V _{GS} = 10 V, I _D = 100 A	2		2.4	mΩ
g _{fs}	Transconductance	V _{DS} = 10 V, I _D = 100 A	329			S
DYNAMIC CHARACTERISTICS						
C _{iss}	Input capacitance	V _{GS} = 0 V, V _{DS} = 50 V, f = 1 MHz		9250	12000	pF
C _{oss}	Output capacitance			1820	2370	pF
C _{rss}	Reverse transfer capacitance			47	61	pF
R _G	Series gate resistance		1.4	2.8		Ω
Q _g	Gate charge total (10 V)	V _{DS} = 50 V, I _D = 100 A	118	153		nC
Q _{gd}	Gate charge gate-to-drain		17			nC
Q _{gs}	Gate charge gate-to-source		37			nC
Q _{g(th)}	Gate charge at V _{th}		24			nC
Q _{oss}	Output charge	V _{DS} = 50 V, V _{GS} = 0 V	335			nC
t _{d(on)}	Turn on delay time	V _{DS} = 50 V, V _{GS} = 10 V, I _{DS} = 100 A, R _G = 0 Ω	13			ns
t _r	Rise time		8			ns
t _{d(off)}	Turn off delay time		32			ns
t _f	Fall time		6			ns
DIODE CHARACTERISTICS						
V _{SD}	Diode forward voltage	I _{SD} = 100 A, V _{GS} = 0 V	0.9	1.1		V
Q _{rr}	Reverse recovery charge	V _{DS} = 50 V, I _F = 100 A, di/dt = 300 A/μs	548			nC
t _{rr}	Reverse recovery time		103			ns

5.2 Thermal Information

($T_A = 25^\circ\text{C}$ unless otherwise stated)

THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance			0.4	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Junction-to-ambient thermal resistance			62	$^\circ\text{C}/\text{W}$

5.3 Typical MOSFET Characteristics

($T_A = 25^\circ\text{C}$ unless otherwise stated)

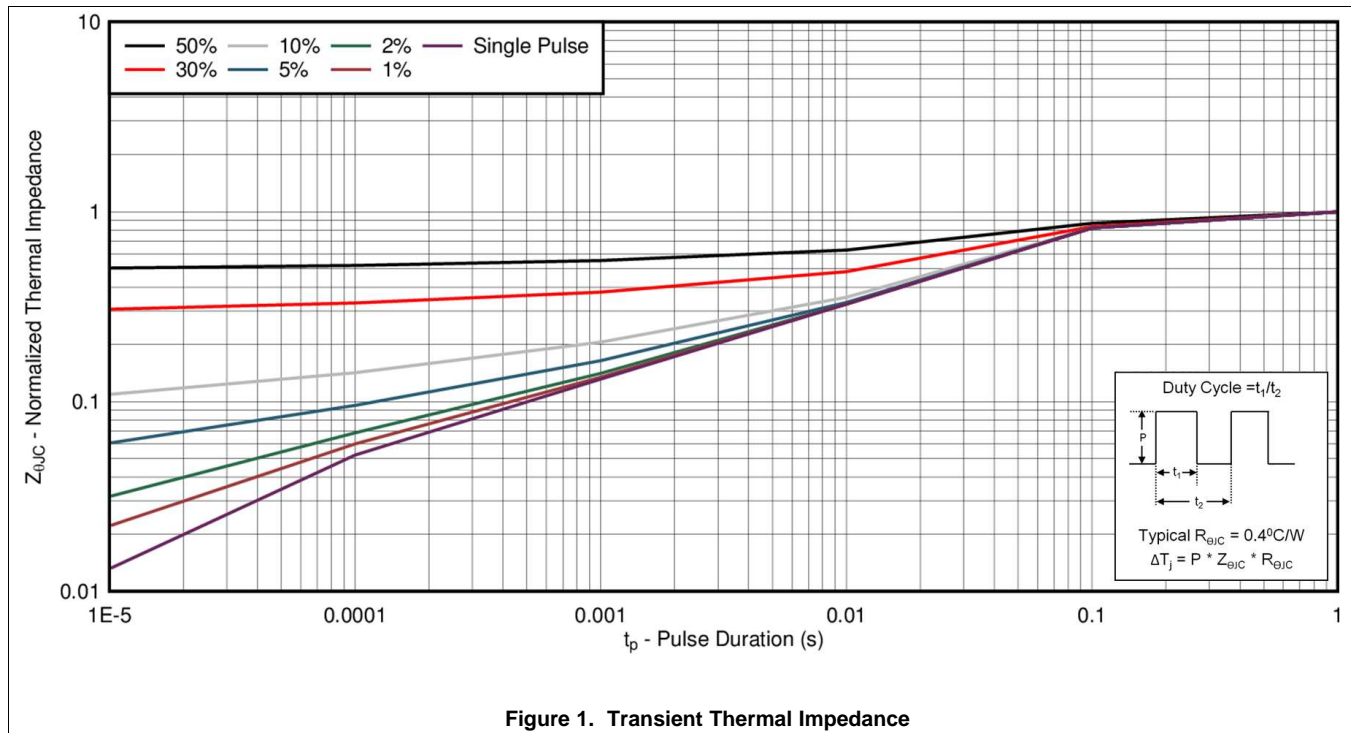


Figure 1. Transient Thermal Impedance

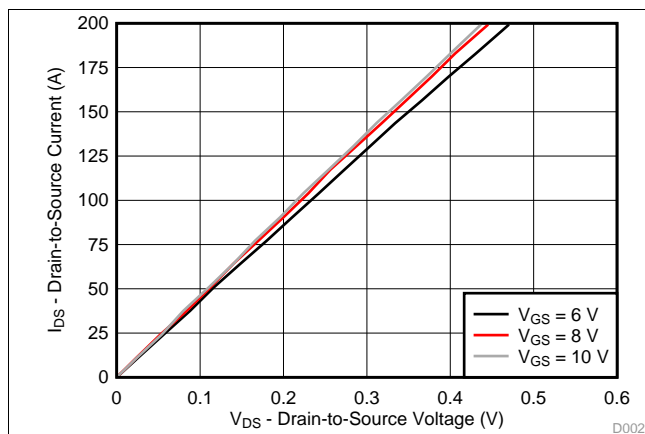


Figure 2. Saturation Characteristics

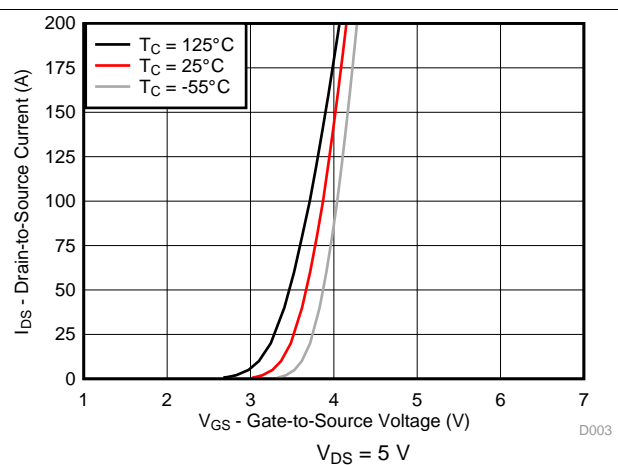
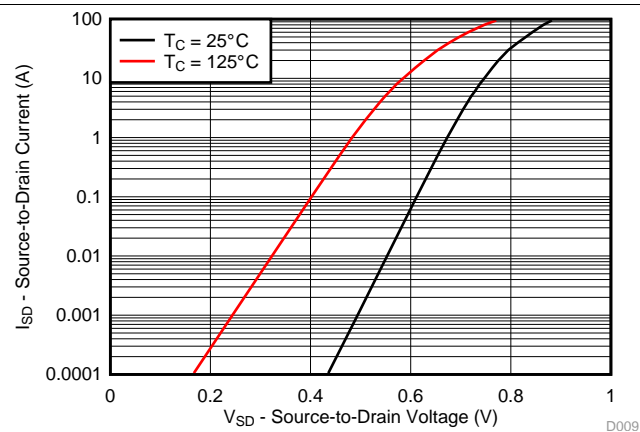
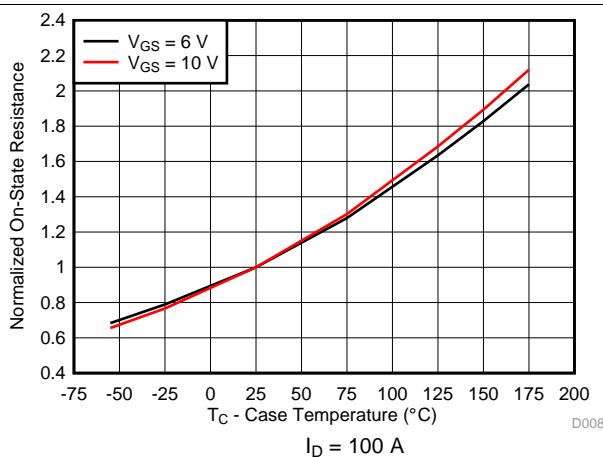
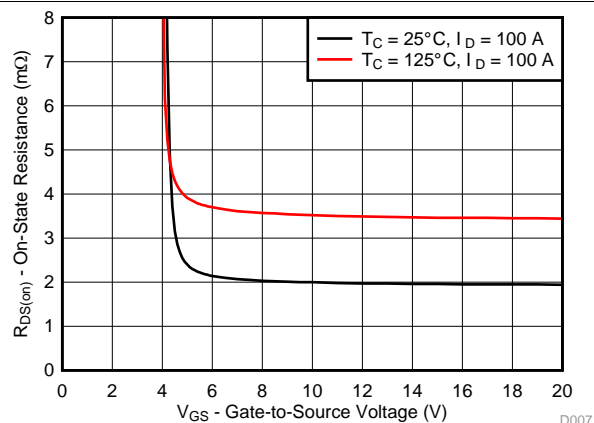
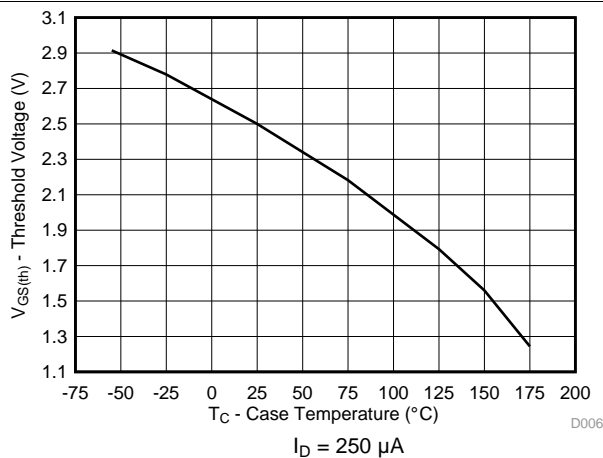
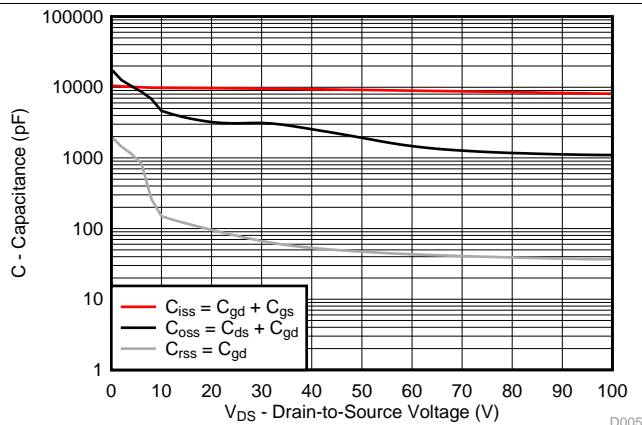
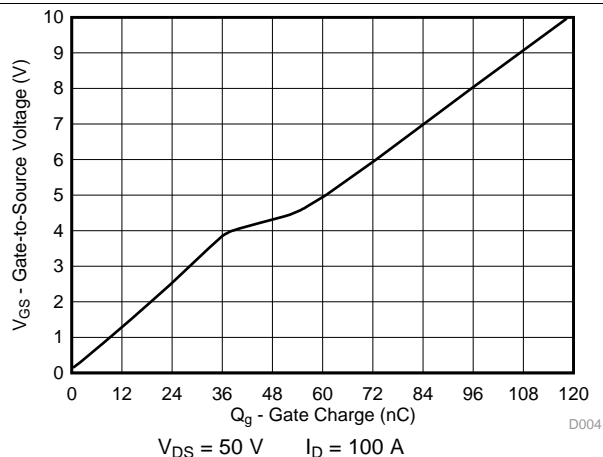


Figure 3. Transfer Characteristics

Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)



Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

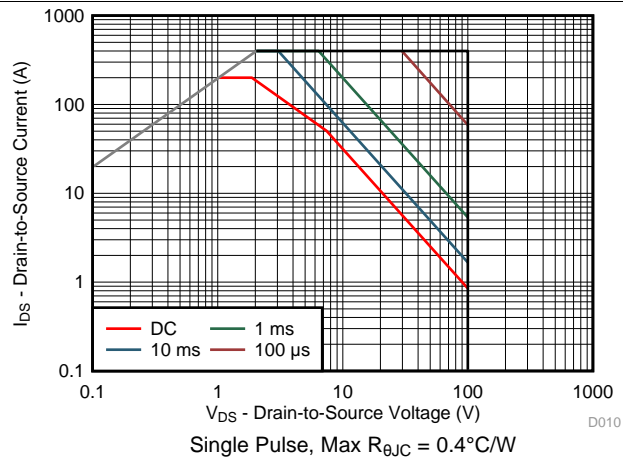


Figure 10. Maximum Safe Operating Area

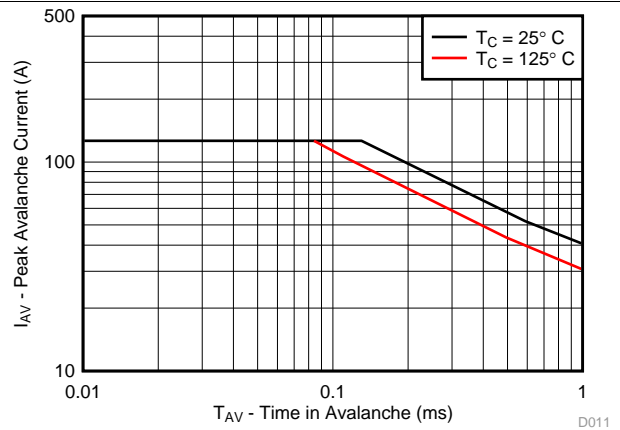


Figure 11. Single Pulse Unclamped Inductive Switching

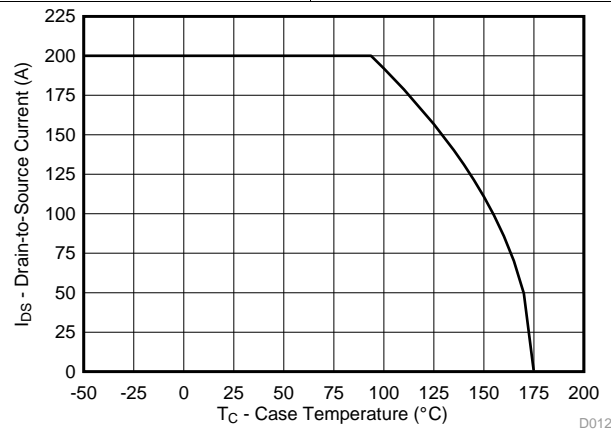


Figure 12. Maximum Drain Current vs Temperature

6 Device and Documentation Support

6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.2 Trademarks

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6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.4 Glossary

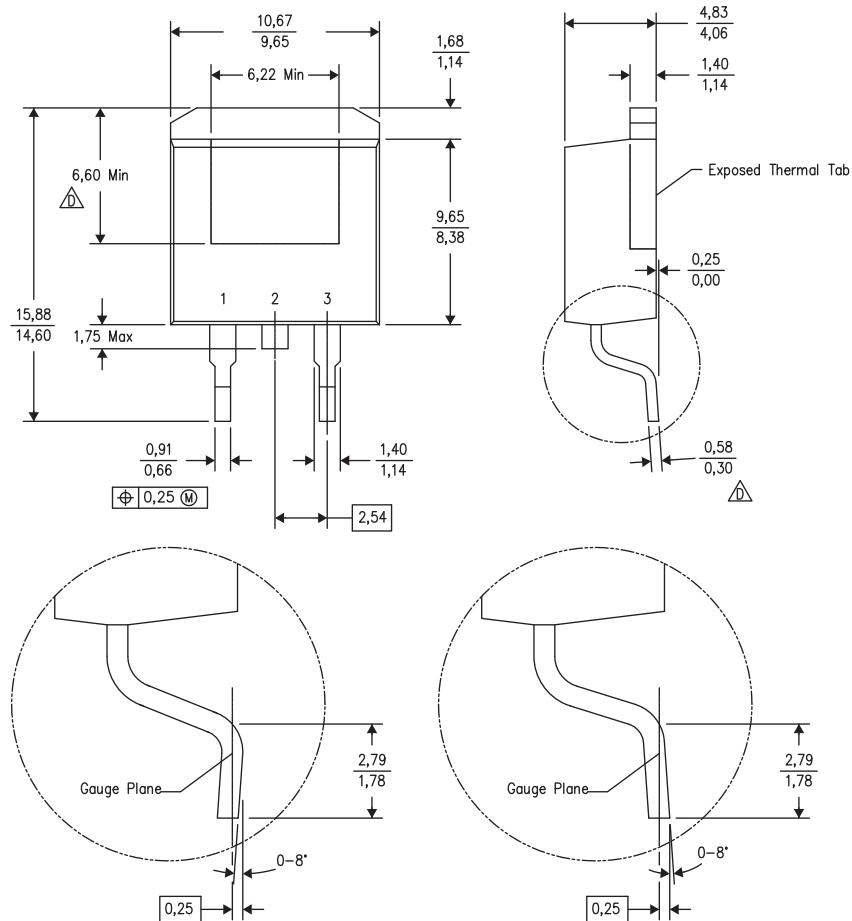
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 KTT Package Dimensions



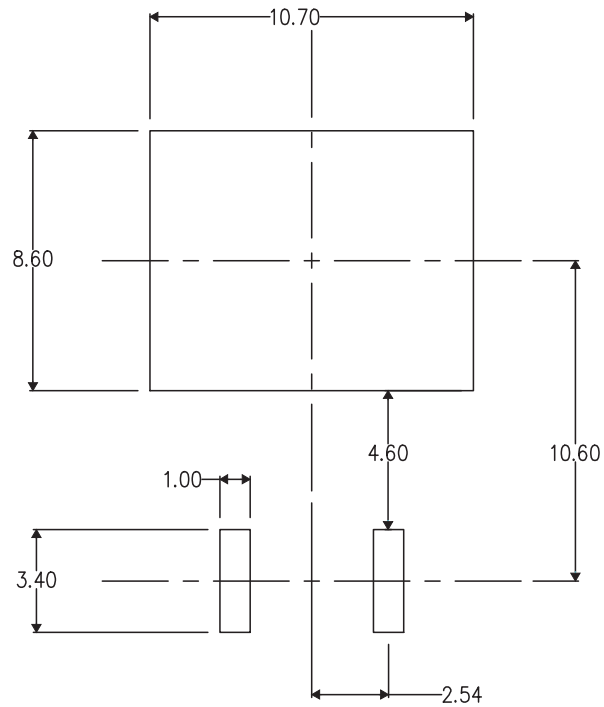
Notes:

1. All linear dimensions are in inches
2. This drawing is subject to change without notice
3. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0.005 mm per side.
4. "D" Falls within JEDEC TO-263 variation AB, except minimum lead thickness and minimum exposed pad length.

Pin Configuration

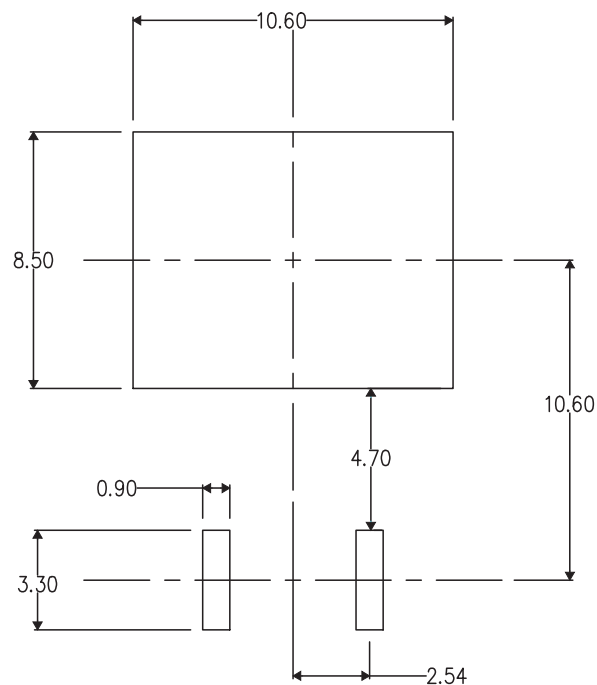
Position	Designation
Pin 1	Gate
Pin 2 / Tab	Drain
Pin 3	Source

7.2 Recommended PCB Pattern



For recommended circuit layout for PCB designs, see application note *Reducing Ringing Through PCB Layout Techniques*, [SLPA005](#).

7.3 Recommended Stencil Opening



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD19536KTT	ACTIVE	DDPAK/ TO-263	KTT	3	500	Pb-Free (RoHS Exempt)	CU SN	Level-2-260C-1 YEAR		CSD19536KTT	Samples
CSD19536KTTT	ACTIVE	DDPAK/ TO-263	KTT	3	50	Pb-Free (RoHS Exempt)	CU SN	Level-2-260C-1 YEAR		CSD19536KTT	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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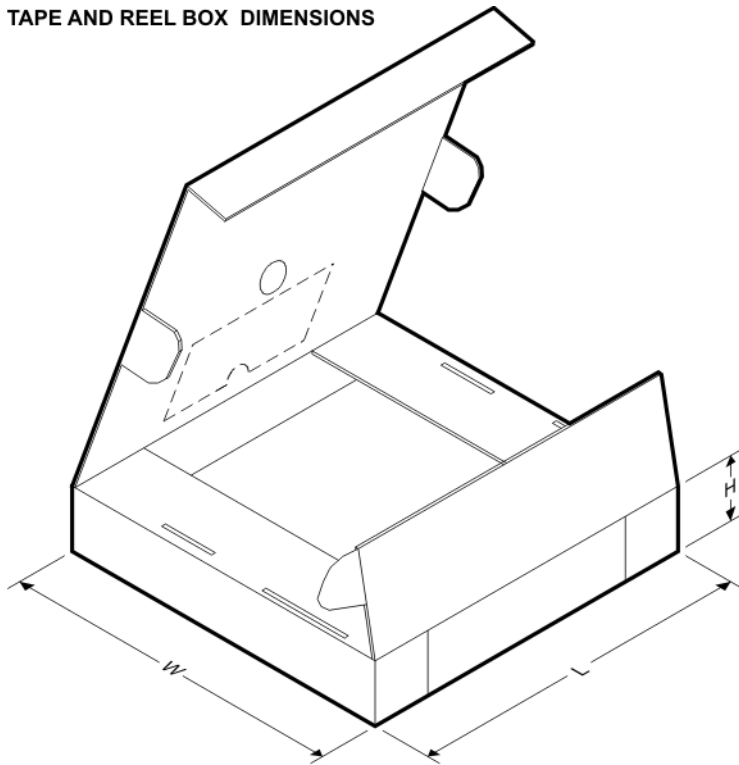
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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD19536KTT	DDPAK/TO-263	KTT	3	500	330.0	24.4	10.8	16.3	5.11	16.0	24.0	Q2
CSD19536KTTT	DDPAK/TO-263	KTT	3	50	330.0	24.4	10.8	16.3	5.11	16.0	24.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD19536KTT	DDPAK/TO-263	KTT	3	500	340.0	340.0	38.0
CSD19536KTTT	DDPAK/TO-263	KTT	3	50	340.0	340.0	38.0

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